TLV742P 200mA小型低ドロップアウト・リニア電圧レギュレータ

1 特長

- 入力電圧範囲: 2V～5.5V
- 固定出力電圧: 50mV刻みで0.85V～5V[(1)]
- 精度: 標準値0.5%
- 高PSRR:
  - 1MHz時に55dB
- イネーブル時I_Q: 25µA
- ディセーブル時I_Q: 1µA
- アクティブ出力放電
- サーマル・シャットダウンおよび過電流保護機能
- パッケージ:
  - 1mm×1mm DQN (X2SON)

2 アプリケーション

- POS
- カメラおよびマシン・ビジョン・モジュール
- ゲームおよび玩具
- ビル・オートメーションおよびビデオ監視
- テレビおよびセットトップ・ボックス

3 概要

TLV742P低ドロップアウト(LDO)リニア電圧レギュレータは、広い出力電圧範囲のサポートにより、優れた性能を実現しています。LDOは、シングルセル・リチウムイオン・バッテリの入出力電圧を0.85Vまで直接調整できます。DC-DCコンバータ出力のポストレギュレーションに使用すれば、1MHz時55dBという高いPSRRでリップルを抑制し、安定した低ノイズのよく調整されたV_{OUT}を実現します。

TLV742Pはアクティブ出力放電機能を備えているため、システムがディセーブル、スタンバイ・モード、またはスリープ・モードの場合に出力を低い状態に維持することができます。 また、過電流保護機能により出力短絡時にデバイスを保護し、サーマル・シャットダウンによって過熱を防止します。

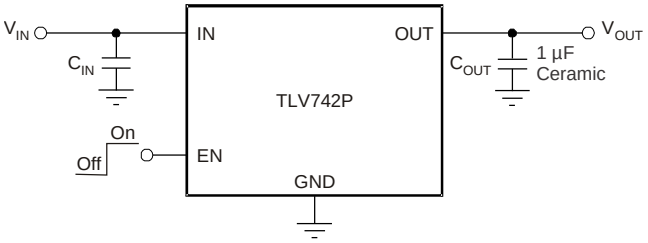
TLV742P電圧レギュレータは1mm×1mmのX2SONパッケージで供給されているため、PCB面積を最小限に抑えることができます。

製品情報[(1)]

型番	パッケージ	本体サイズ(公称)
TLV742P	X2SON (4)	1.00mm×1.00mm

(1) 提供されているすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。

代表的なアプリケーション回路



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4 改訂履歴

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

日付	改訂内容	注
2017年9月	*	初版

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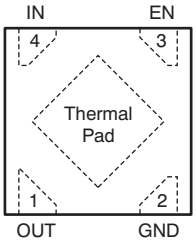
5 Pin Configuration and Functions

DQN Package
4-Pin X2SON With Exposed Thermal Pad
Top View



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
EN	3	I	Enable pin. Driving EN over 0.9 V turns on the regulator. Driving EN below 0.4 V puts the regulator into shutdown mode. For TLV742P, output voltage is discharged through an internal 120-Ω resistor when device is shut down.
GND	2	—	Ground pin
IN	4	I	Input pin. For good transient performance, place a small 1-µF ceramic capacitor from this pin to ground. See *Input and Output Capacitor Requirements* for more details.
OUT	1	O	Regulated output voltage pin. A small 1-µF ceramic capacitor is required from this pin to ground to ensure stability. See *Input and Output Capacitor Requirements* for more details.
Thermal pad	—	—	The thermal pad is electrically connected to the GND node. Connect to the GND plane for improved thermal performance.

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6 Specifications

6.1 Absolute Maximum Ratings

over operating junction temperature range (unless otherwise noted)[1]

		MIN	MAX	UNIT
Voltage[2]	IN	–0.3	6	V
	EN	–0.3	6	V
	OUT	–0.3	6	V
Current (source)	OUT	Internally limited		
Output short-circuit duration		Indefinite		
Operating junction, T_J		–55	150	°C
Storage, T_{stg}		–55	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods my affect device reliability.
(2) All voltages are with respect to GND pin.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM) QSS 009-105 (JESD22-A114A)[1]	±2000	V
		Charged device model (CDM) QSS 009-147 (JESD22-C101B.01)[2]	±500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating junction temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{IN}	Input voltage	2		5.5	V
I_{OUT}	Output current	0		200	mA
T_J	Operating junction temperature range	–40		125	°C

6.4 Thermal Information

THERMAL METRIC[1]		TLV742P DQN (X2SON) 4 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	180.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	152	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	117.2	°C/W
ψ_{JT}	Junction-to-top characterization parameter	5.1	°C/W
ψ_{JB}	Junction-to-board characterization parameter	117	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	99.7	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

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6.5 Electrical Characteristics

at $V_{IN} = V_{OUT(NOM)} + 0.5$ V or 2 V (whichever is greater); I_{OUT} = 1 mA, $V_{EN} = V_{IN}$, C_{OUT} = 0.47 µF, and T_J = –40°C to +85°C. Typical values are at T_J = 25°C, (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V_{IN}	Input voltage range				2		5.5	V
V_{OUT}	Output voltage range				0.85		5	V
	DC output accuracy					0.5%		
		$V_{OUT} \geq 0.85$ V			–1.5%		1.5%	
$\Delta V_{O(\Delta VI)}$	Line regulation					1	5	mV
$\Delta V_{O(\Delta IO)}$	Load regulation	0 mA ≤ I_{OUT} ≤ 150 mA				10	20	mV
$V_{(DO)}$	Dropout voltage	$V_{IN} = 0.98 \times V_{OUT(NOM)}$	2 V < V_{OUT} ≤ 2.4 V	I_{OUT} = 30 mA		65		mV
				I_{OUT} = 150 mA		325	360	mV
			2.4 V < V_{OUT} ≤ 2.8 V	I_{OUT} = 30 mA		50		mV
				I_{OUT} = 150 mA		250	300	mV
			2.8 V < V_{OUT} ≤ 3.3 V	I_{OUT} = 30 mA		45		mV
				I_{OUT} = 150 mA		220	270	mV
			3.3 V < V_{OUT} ≤ 5 V	I_{OUT} = 30 mA		40		mV
				I_{OUT} = 150 mA		200	250	mV
I_{CL}	Output current limit	$V_{OUT} = 0.9 \times V_{OUT(NOM)}$			240	300	450	mA
$I_{(GND)}$	Ground pin current	I_{OUT} = 0 mA				25	50	µA
$I_{(EN)}$	EN pin current	V_{EN} = 5.5 V				0.01		µA
$I_{SHUTDOWN}$	Shutdown current	V_{EN} ≤ 0.4 V 2 V ≤ V_{IN} ≤ 4.5 V				1		µA
$V_{IL(EN)}$	EN pin low-level input voltage (disable device)				0		0.4	V
$V_{IH(EN)}$	EN pin high-level input voltage (enable device)				0.9		V_{IN}	V
PSRR	Power-supply rejection ratio	V_{IN} = 3.3 V V_{OUT} = 2.8 V I_{OUT} = 30 mA		f = 100 Hz		70		dB
				f = 10 kHz		55		
				f = 1 MHz		55		
V_n	Output noise voltage	BW = 100 Hz to 100 kHz, V_{IN} = 2.3 V V_{OUT} = 1.8 V I_{OUT} = 10 mA				45		μV_{RMS}
t_{STR}	Startup time(1)	C_{OUT} = 1 µF I_{OUT} = 150 mA				100		µs
$R_{PULLDOWN}$	Pulldown resistance (TLV742P only)					120		Ω
T_J	Operating junction temperature				–40		125	°C

(1) Start-up time = time from EN assertion to 0.98 × V_{OUT}.

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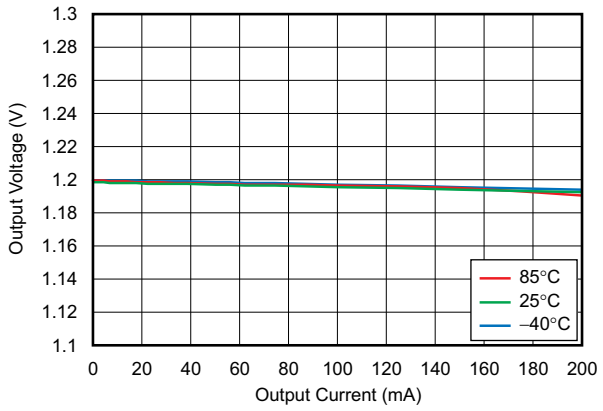
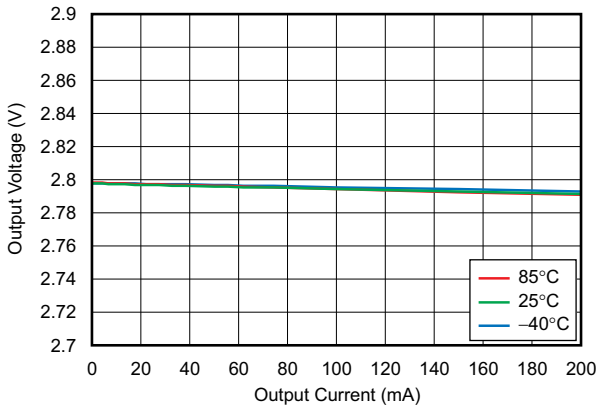
6.6 Typical Characteristics

at T_J = –40°C to +85°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2 V (whichever is greater), I_{OUT} = 10 mA, V_{EN} = V_{IN}, and C_{OUT} = 1 µF
Typical values are at T_J = 25°C, (unless otherwise noted)



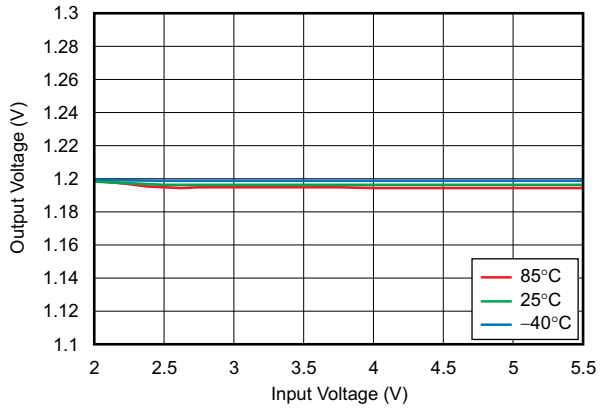
V_{OUT} = 1.2 V

図 1. Load Regulation



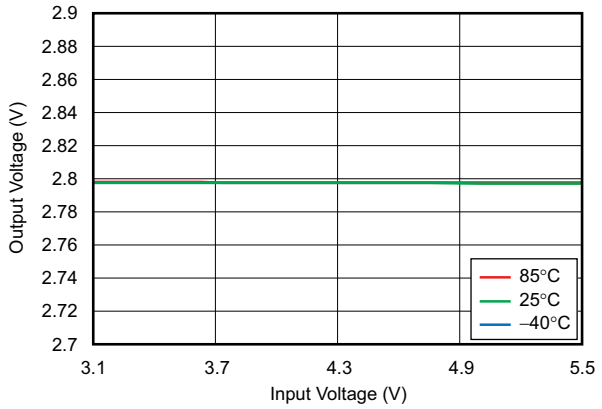
V_{OUT} = 2.8 V

図 2. Load Regulation



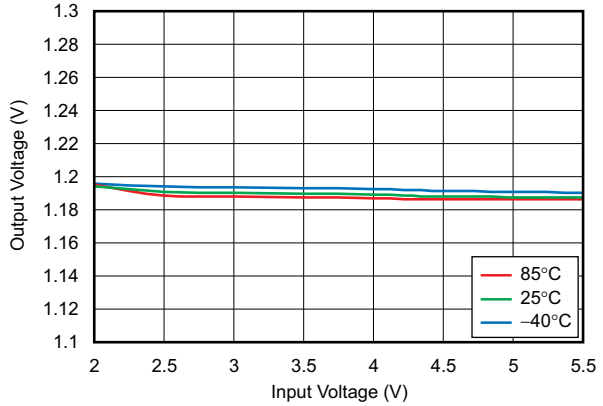
V_{OUT} = 1.2 V, I_{OUT} = 10 mA

図 3. Line Regulation



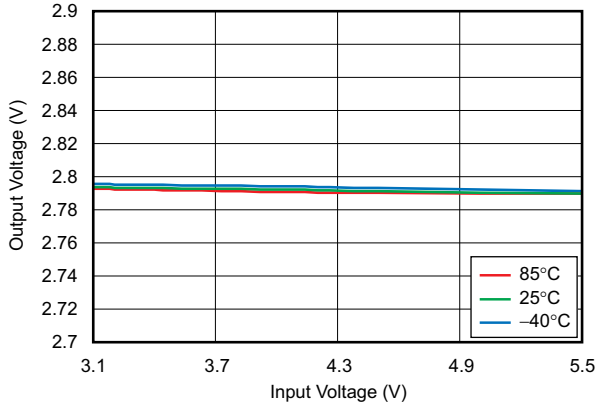
V_{OUT} = 2.8 V, I_{OUT} = 10 mA

図 4. Line Regulation



V_{OUT} = 1.2 V, I_{OUT} = 150 mA

図 5. Line Regulation



V_{OUT} = 2.8 V, I_{OUT} = 150 mA

図 6. Line Regulation

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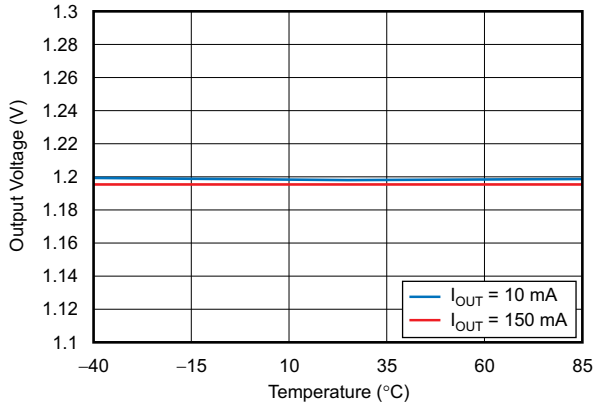
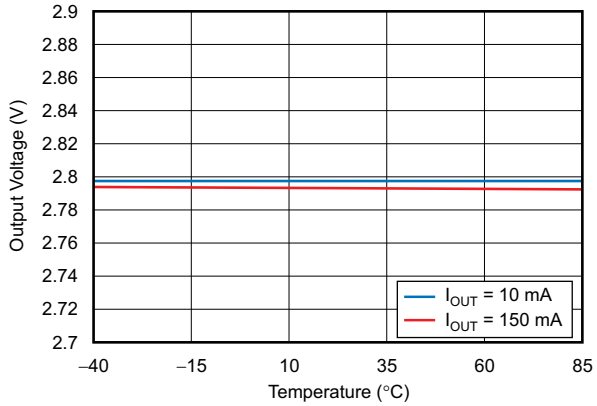
Typical Characteristics (continued)

at T_J = –40°C to +85°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2 V (whichever is greater), I_{OUT} = 10 mA, V_{EN} = V_{IN}, and C_{OUT} = 1 µF
Typical values are at T_J = 25°C, (unless otherwise noted)



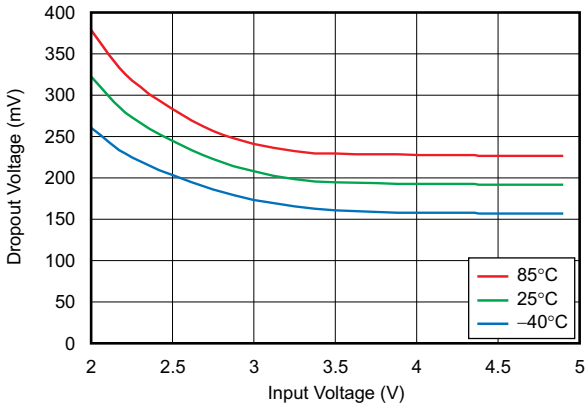
V_{OUT} = 1.2 V

図 7. Output Voltage vs Temperature



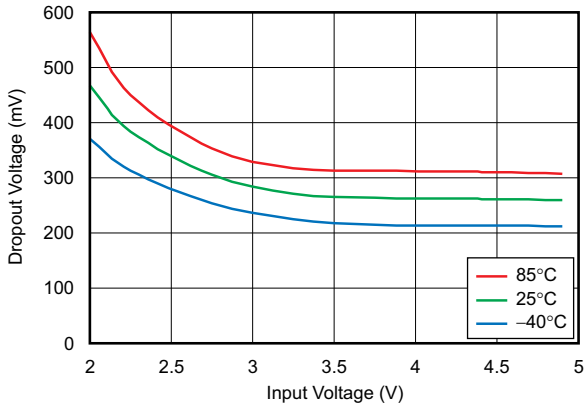
V_{OUT} = 2.8 V

図 8. Output Voltage vs Temperature



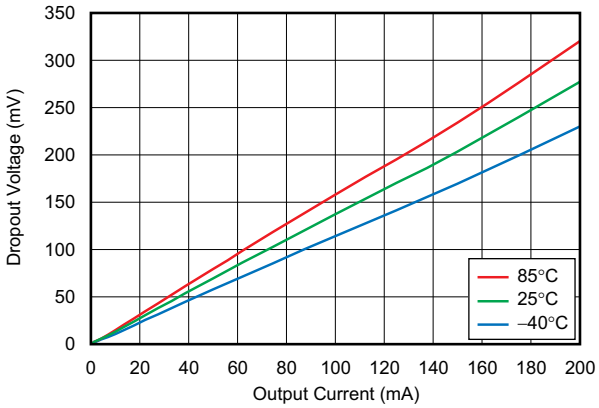
I_{OUT} = 150 mA

図 9. Dropout Voltage vs Input Voltage



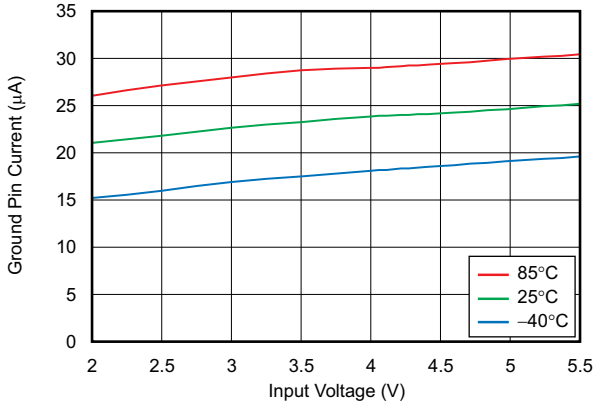
I_{OUT} = 200 mA

図 10. Dropout Voltage vs Input Voltage



V_{OUT} = 2.8 V

図 11. Dropout Voltage vs Output Current



V_{OUT} = 1.2 V, I_{OUT} = 0 mA

図 12. Ground Pin Current vs Input Voltage

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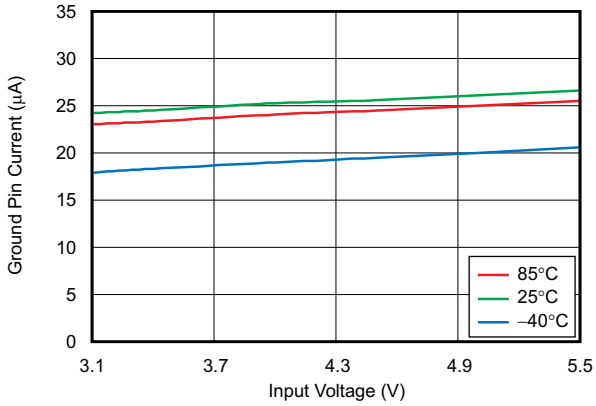
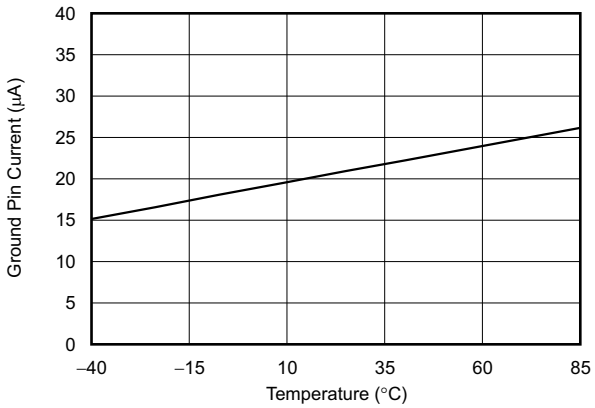
Typical Characteristics (continued)

at T_J = –40°C to +85°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2 V (whichever is greater), I_{OUT} = 10 mA, V_{EN} = V_{IN}, and C_{OUT} = 1 µF
Typical values are at T_J = 25°C, (unless otherwise noted)



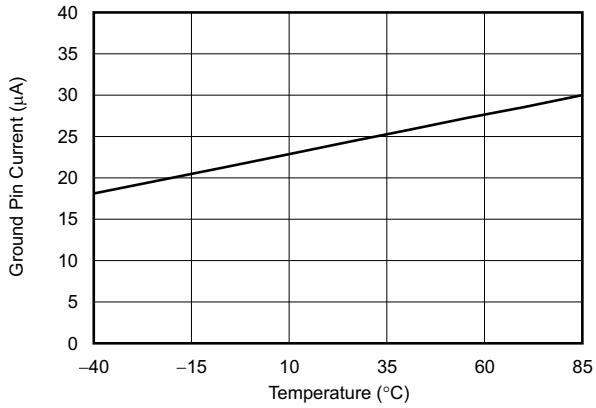
V_{OUT} = 2.8 V, I_{OUT} = 0 mA

図 13. Ground Pin Current vs Input Voltage



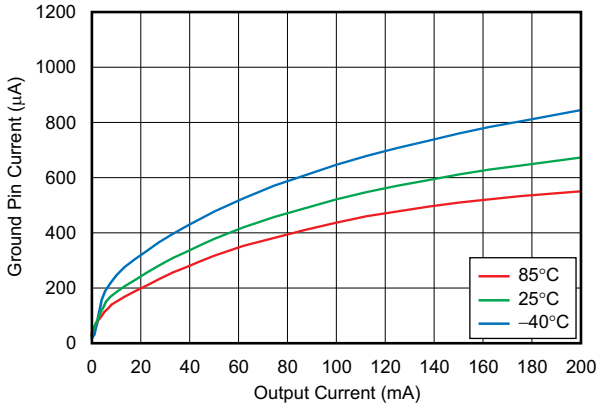
V_{OUT} = 1.2 V, I_{OUT} = 0 mA

図 14. Ground Pin Current vs Temperature



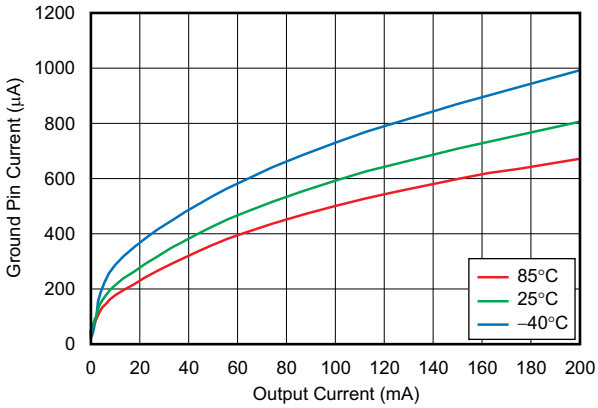
V_{OUT} = 2.8 V, I_{OUT} = 0 mA

図 15. Ground Pin Current vs Temperature



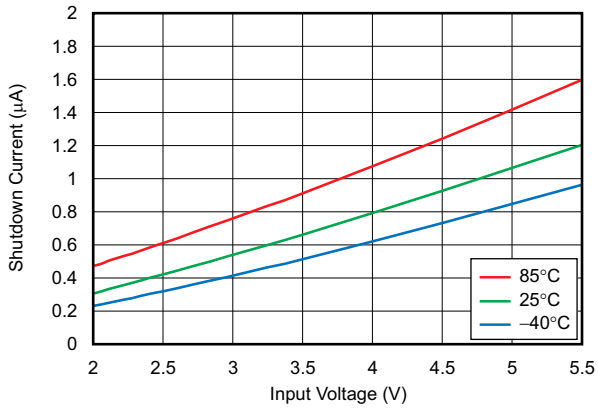
V_{OUT} = 1.2 V

図 16. Ground Pin Current vs Output Current



V_{OUT} = 2.8 V

図 17. Ground Pin Current vs Output Current



V_{OUT} = 1.2 V

図 18. Shutdown Current vs Input Voltage

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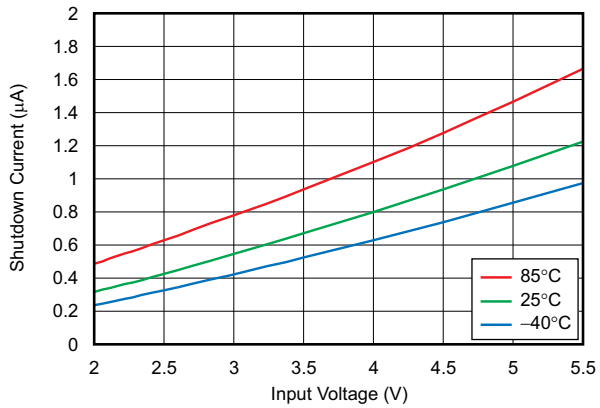
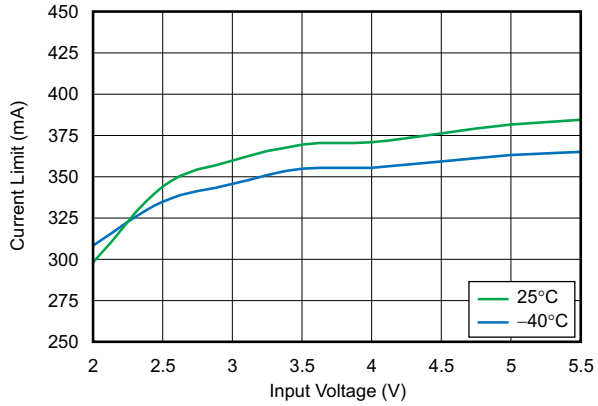
Typical Characteristics (continued)

at T_J = –40°C to +85°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2 V (whichever is greater), I_{OUT} = 10 mA, V_{EN} = V_{IN}, and C_{OUT} = 1 µF
Typical values are at T_J = 25°C, (unless otherwise noted)



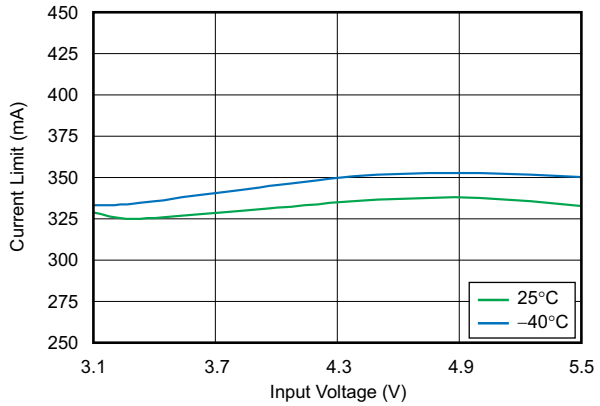
V_{OUT} = 2.8 V

図 19. Shutdown Current vs Input Voltage



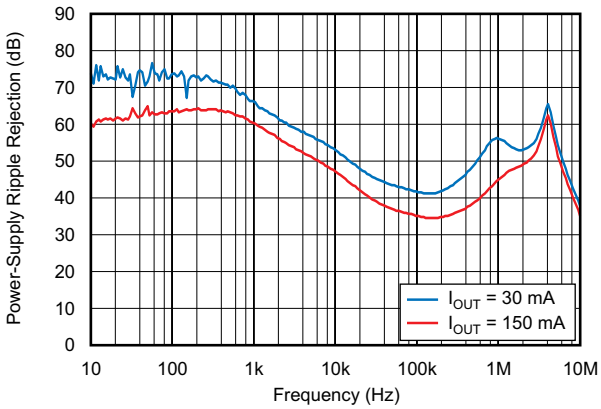
V_{OUT} = 1.2 V

図 20. Current Limit vs Input Voltage



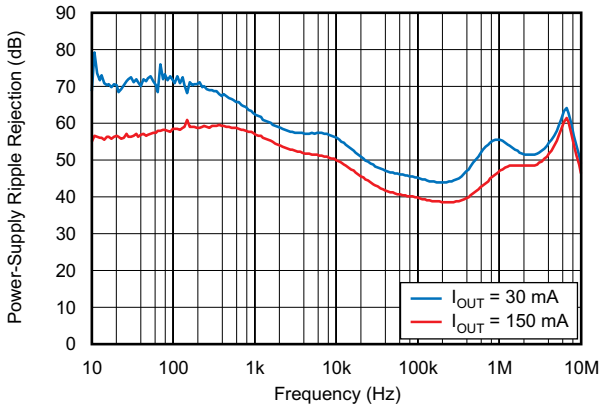
V_{OUT} = 2.8 V

図 21. Current Limit vs Input Voltage



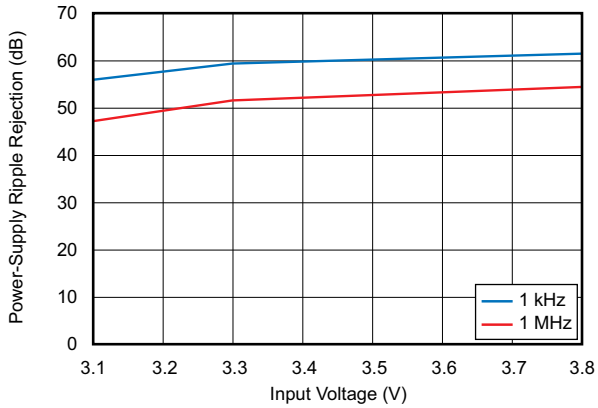
V_{OUT} = 1.2 V

図 22. Power-Supply Ripple Rejection vs Frequency



V_{OUT} = 2.8 V

図 23. Power-Supply Ripple Rejection vs Frequency



V_{OUT} = 2.8 V, I_{OUT} = 30 mA

図 24. Power-Supply Ripple Rejection vs Input Voltage

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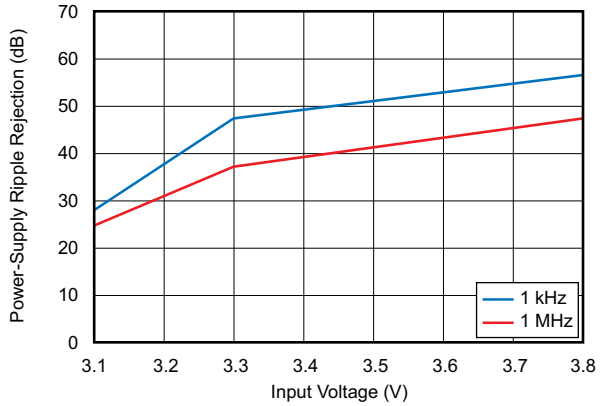
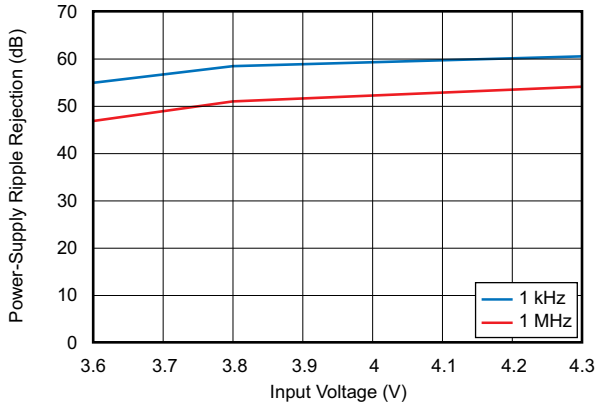
Typical Characteristics (continued)

at T_J = –40°C to +85°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2 V (whichever is greater), I_{OUT} = 10 mA, V_{EN} = V_{IN}, and C_{OUT} = 1 µF
Typical values are at T_J = 25°C, (unless otherwise noted)



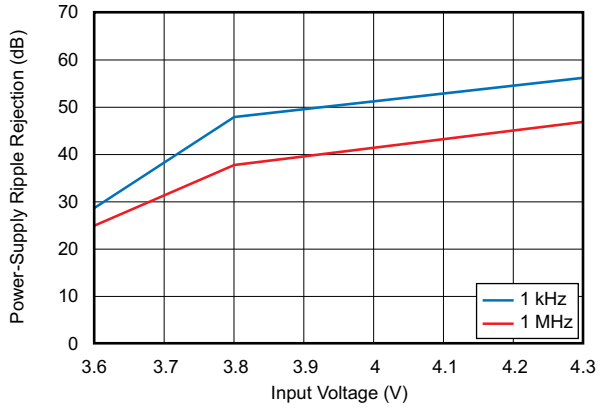
V_{OUT} = 2.8 V, I_{OUT} = 150 mA

図 25. Power-Supply Ripple Rejection vs Input Voltage



V_{OUT} = 3.3 V, I_{OUT} = 30 mA

図 26. Power-Supply Ripple Rejection vs Input Voltage



V_{OUT} = 3.3 V, I_{OUT} = 150 mA

図 27. Power-Supply Ripple Rejection vs Input Voltage

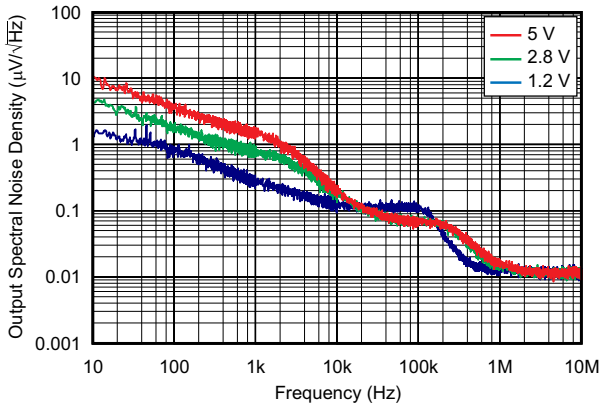
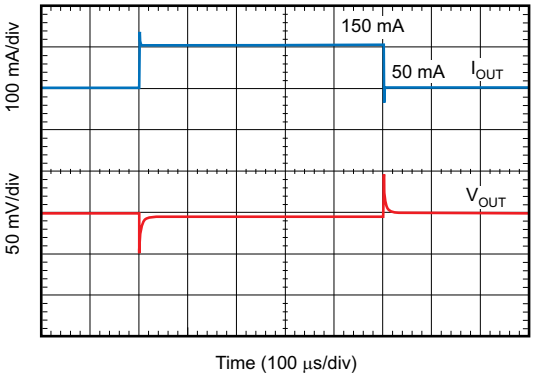
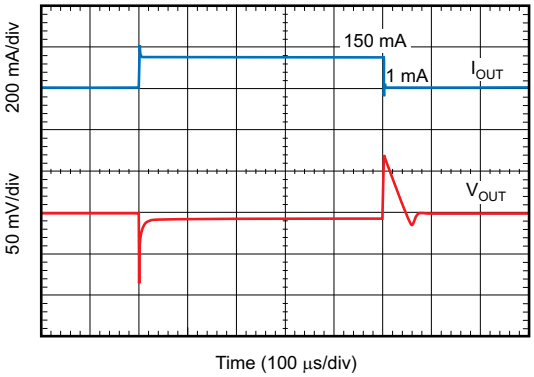


図 28. Output Spectral Noise Density vs Frequency



V_{OUT} = 1.2 V

図 29. Load Transient Response



V_{OUT} = 1.2 V

図 30. Load Transient Response

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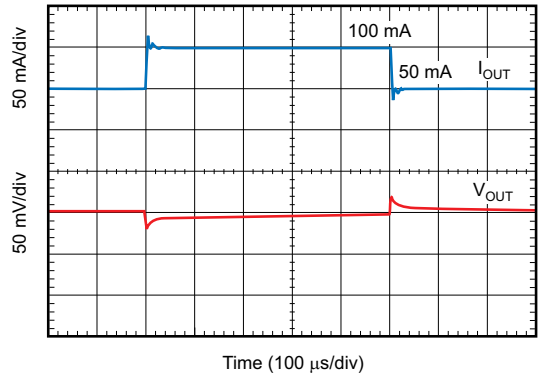
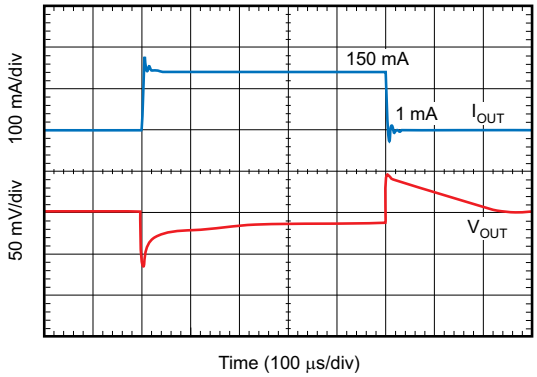
Typical Characteristics (continued)

at T_J = –40°C to +85°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2 V (whichever is greater), I_{OUT} = 10 mA, V_{EN} = V_{IN}, and C_{OUT} = 1 µF
Typical values are at T_J = 25°C, (unless otherwise noted)



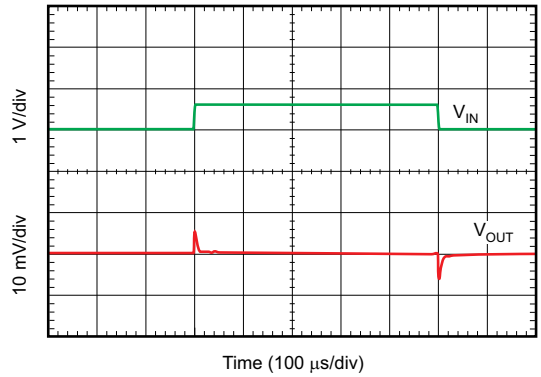
V_{OUT} = 2.8 V

図 31. Load Transient Response



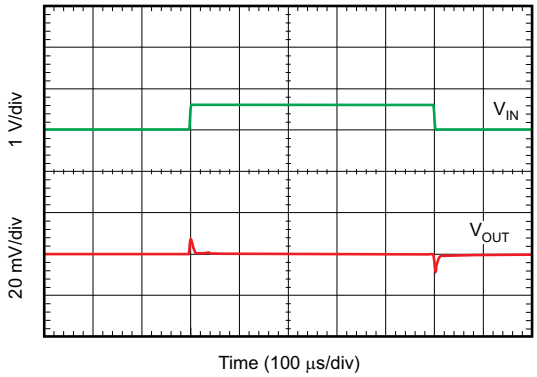
V_{OUT} = 2.8 V

図 32. Load Transient Response



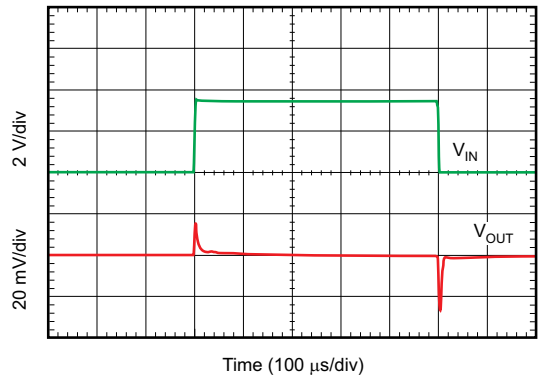
V_{OUT} = 1.2 V, I_{OUT} = 150 mA

図 33. Line Transient Response



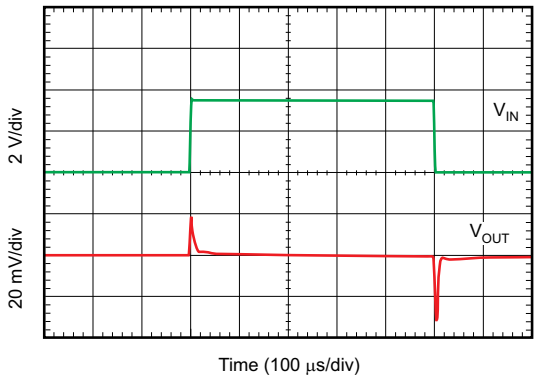
V_{OUT} = 1.2 V, I_{OUT} = 200 mA

図 34. Line Transient Response



V_{OUT} = 1.2 V, I_{OUT} = 150 mA

図 35. Line Transient Response

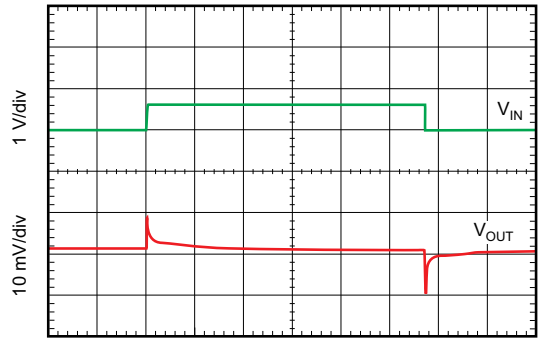


V_{OUT} = 1.2 V, I_{OUT} = 200 mA

図 36. Line Transient Response

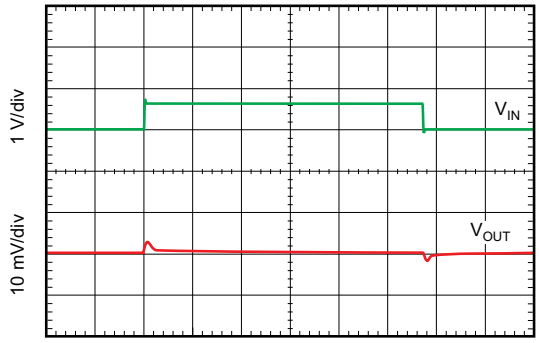
Typical Characteristics (continued)

at T_J = –40°C to +85°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 2 V (whichever is greater), I_{OUT} = 10 mA, V_{EN} = V_{IN}, and C_{OUT} = 1 µF
Typical values are at T_J = 25°C, (unless otherwise noted)



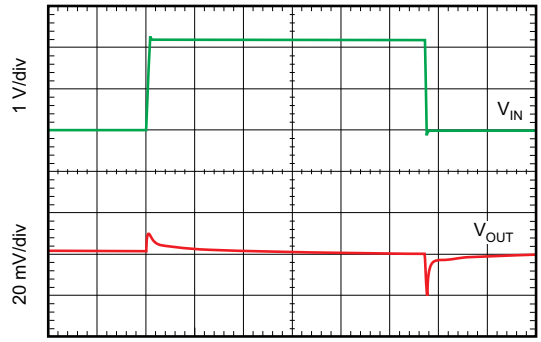
Time (100 µs/div)
V_{OUT} = 2.8 V, I_{OUT} = 150 mA

図 37. Line Transient Response



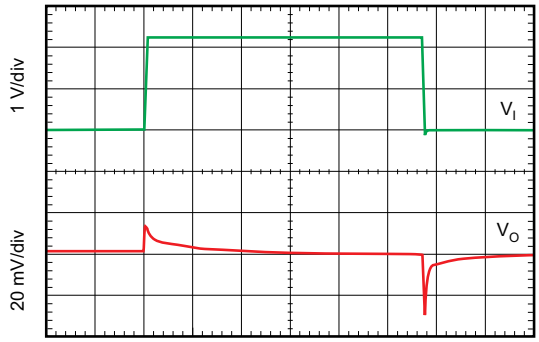
Time (100 µs/div)
V_{OUT} = 2.8 V, I_{OUT} = 200 mA

図 38. Line Transient Response



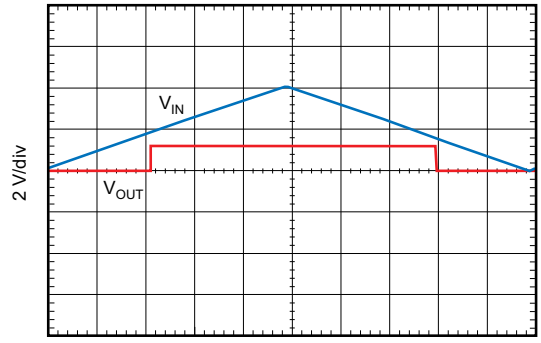
Time (100 µs/div)
V_{OUT} = 2.8 V, I_{OUT} = 200 mA

図 39. Line Transient Response



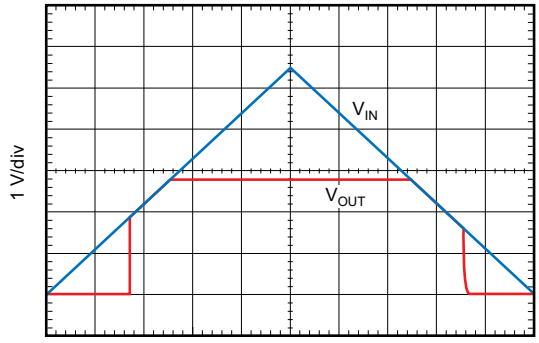
Time (100 µs/div)
V_{OUT} = 2.8 V, I_{OUT} = 200 mA

図 40. Line Transient Response



Time (100 ms/div)
V_{OUT} = 1.2 V, I_{OUT} = 30 mA

図 41. V_{IN} Ramp Up, Ramp Down Response



Time (100 ms/div)
V_{OUT} = 2.8 V, I_{OUT} = 30 mA

図 42. V_{IN} Ramp Up, Ramp Down Response

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7 Detailed Description

7.1 Overview

The TLV742P device belongs to a family of LDOs. This device consumes low quiescent current and delivers excellent line and load transient performance. These characteristics [combined with low noise and very good PSRR with little (V_{IN} – V_{OUT}) headroom] make this device ideal for portable RF applications.

7.2 Functional Block Diagrams

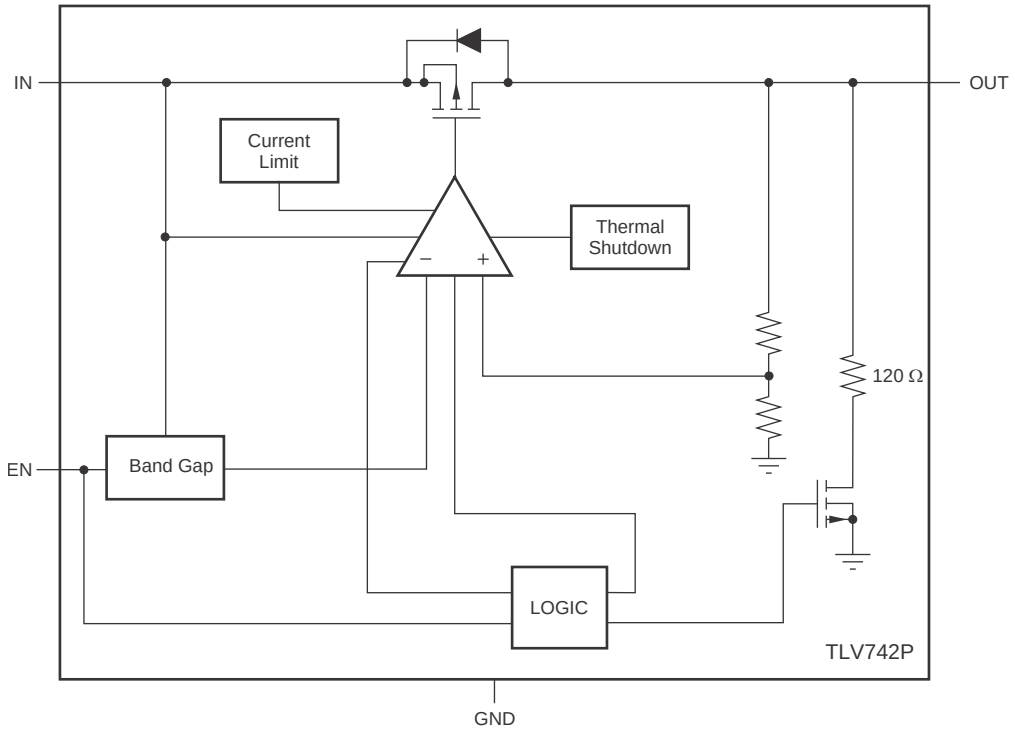

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図 43. TLV742P Block Diagram

7.3 Feature Description

This LDO regulator offers current limit and thermal protection. The operating junction temperature of this device is –40°C to +125°C.

7.3.1 Internal Current Limit

The internal current limit helps to protect the regulator during fault conditions. During current limit, the output sources a fixed amount of current that is largely independent of the output voltage. In such a case, the output voltage is not regulated, and is $V_{OUT} = I_{CL} \times R_L$. The PMOS pass transistor dissipates (V_{IN} – V_{OUT}) × I_{LIMIT} until thermal shutdown is triggered and the device turns off. When the device cools, the internal thermal shutdown circuit turns the device back on. If the fault condition continues, the device cycles between current limit and thermal shutdown; see *Thermal Information* for more details.

The PMOS pass element has a built-in body diode that conducts current when the voltage at OUT exceeds the voltage at IN. This current is not limited, so if extended reverse voltage operation is anticipated, external limiting to 5% of the rated output current is recommended.

Feature Description (continued)

7.3.2 Shutdown

The enable pin (EN) is active high. The device is enabled when voltage at the EN pin goes above 0.9 V. The device is turned off when the EN pin is held at less than 0.4 V. When shutdown capability is not required, EN can be connected to the IN pin.

The TLV742P version has internal active pulldown circuitry that discharges the output with a time constant as given by 式 1:

$$\tau = \frac{(120 \bullet R_L)}{(120 + R_L)} \bullet C_{OUT} \tag{1}$$

where:

- R_L = Load resistance
- C_{OUT} = Output capacitor

7.4 Device Functional Modes

The TLV742P series is specified over the recommended operating conditions (see *Recommended Operating Conditions*). The specifications may not be met when exposed to conditions outside of the recommended operating range.

To turn on the regulator, the EN pin must be driven over 0.9 V. Driving the EN pin below 0.4 V causes the regulator to enter shutdown mode.

In shutdown, the current consumption of the device typically reduces to 1 µA.

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8 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TLV742P is a LDO with low quiescent current that delivers excellent line and load transient performance. This LDO regulator offers current limit and thermal protection. The operating junction temperature of this device series is –40°C to +125°C.

8.2 Typical Application

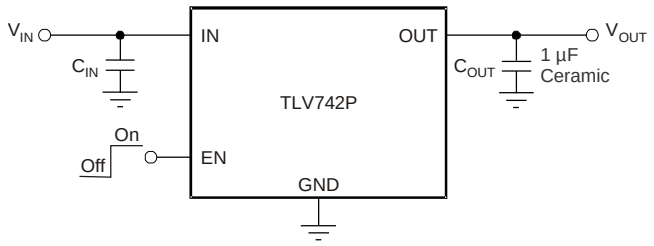

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図 44. Typical Application Circuit

8.2.1 Design Requirements

Provide an input supply with adequate headroom to meet minimum V_{IN} requirements (as listed in 表 1), compensate for the GND pin current, and to power the load.

表 1. Design Parameters

PARAMETER	DESIGN REQUIREMENT
Input voltage	1.8 V to 3.6 V
Output voltage	1.2 V
Output current	100 mA

8.2.2 Detailed Design Procedure

8.2.2.1 Input and Output Capacitor Requirements

Generally, 1-µF X5R- and X7R-type ceramic capacitors are recommended because these capacitors have minimal variation in value and equivalent series resistance (ESR) over temperature.

However, the TLV742P is designed to be stable with an effective capacitance of 0.1 µF or larger at the output. As a result, the device is stable with capacitors of other dielectric types if the effective capacitance under operating bias voltage and temperature is greater than 0.1 µF. This effective capacitance refers to the capacitance that the LDO detects under operating bias voltage and temperature conditions; that is, the capacitance after taking bias voltage and temperature derating into consideration. In addition to using less expensive dielectrics, this stability with 0.1-µF effective capacitance enables the use of smaller footprint capacitors that have higher derating in size- and space-constrained applications.

Using a 0.1-µF rated capacitor at the output of the LDO does not ensure stability because the effective capacitance under the specified operating conditions is less than 0.1 µF. Maximum ESR must be less than 200 mΩ.

Although an input capacitor is not required for stability, good analog design practice is to connect a 0.1-µF to 1-µF, low ESR capacitor across the IN pin and GND pin of the regulator. This capacitor counteracts reactive input sources and improves transient response, noise rejection, and ripple rejection. A higher-value capacitor may be required if large, fast rise-time load transients are anticipated, or if the device is not located close to the power source. If source impedance is more than 2-Ω, a 0.1-µF input capacitor may be required to ensure stability.

8.2.2.2 Dropout Voltage

The TLV742P series of LDOs use a PMOS pass transistor to achieve low dropout. When (V_{IN} – V_{OUT}) is less than the dropout voltage (V_{DO}), the PMOS pass device is in the linear region of operation and the input-to-output resistance is the $R_{DS(ON)}$ of the PMOS pass element. V_{DO} scales approximately with output current because the PMOS device functions similar to a resistor in dropout.

PSRR and transient response degrade when (V_{IN} – V_{OUT}) approaches dropout.

8.2.2.3 Transient Response

Increasing the size of the output capacitor reduces overshoot and undershoot magnitude but increases the duration of the transient response.

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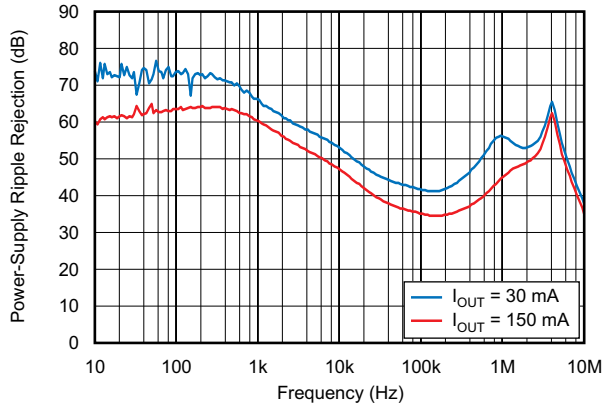
8.2.3 Application Curves



V_{OUT} = 1.2 V

図 45. Power-Supply Ripple Rejection vs Frequency

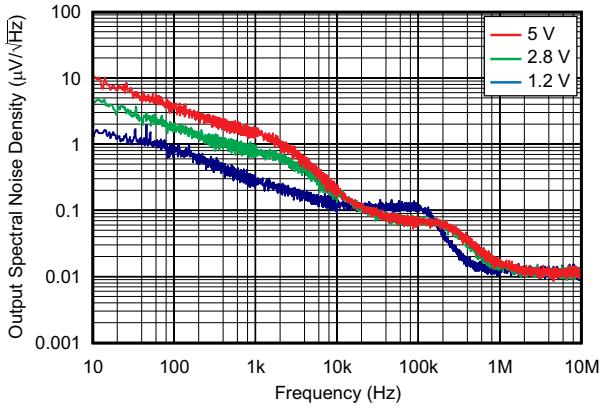
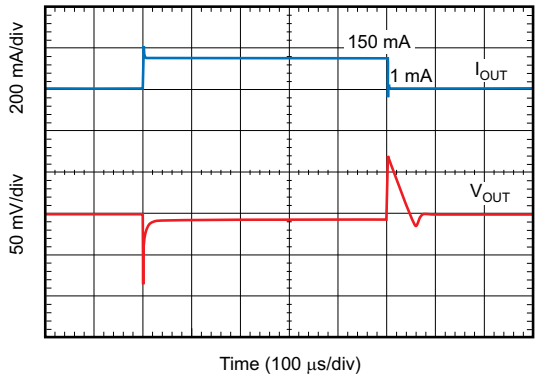
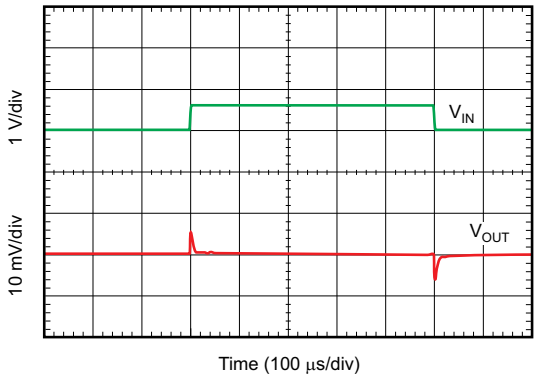


図 46. Output Spectral Noise Density vs Frequency



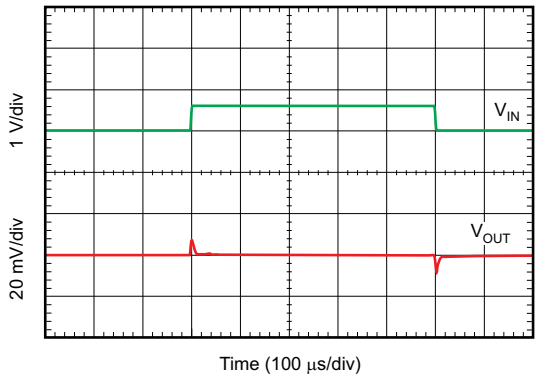
V_{OUT} = 1.2 V

図 47. Load Transient Response



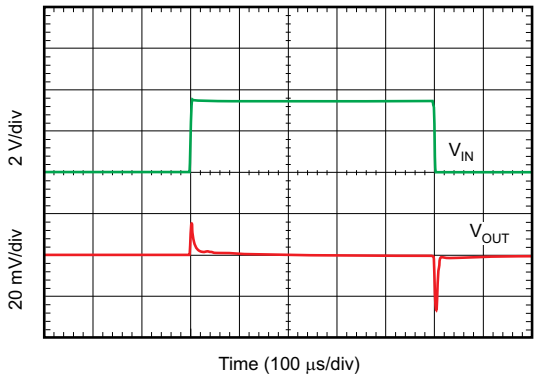
V_{OUT} = 1.2 V, I_{OUT} = 150 mA

図 48. Line Transient Response



V_{OUT} = 1.2 V, I_{OUT} = 200 mA

図 49. Line Transient Response



V_{OUT} = 1.2 V, I_{OUT} = 150 mA

図 50. Line Transient Response

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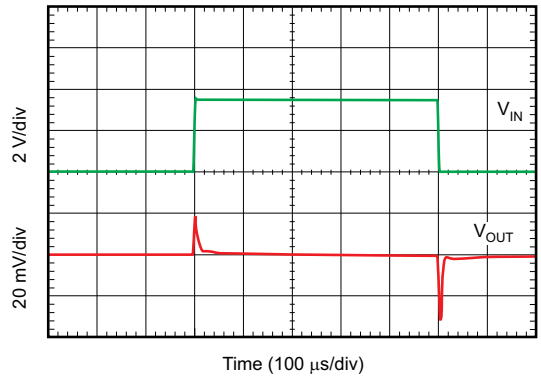
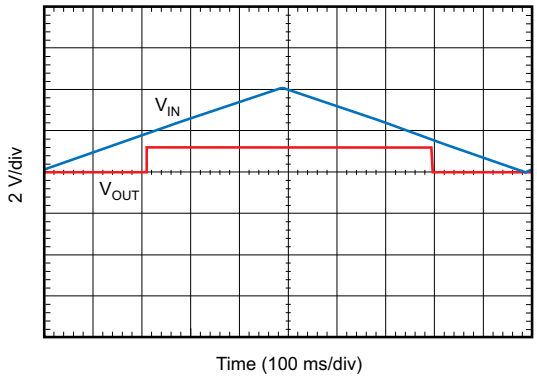


V_{OUT} = 1.2 V, I_{OUT} = 200 mA

図 51. Line Transient Response



V_{OUT} = 1.2 V, I_{OUT} = 30 mA

図 52. V_{IN} Ramp Up, Ramp Down Response

8.3 Do's and Don'ts

Place at least one 1-µF ceramic capacitor as close as possible to the OUT pin of the regulator.

Do not place the output capacitor more than 10 mm away from the regulator.

Connect a 1-µF low equivalent series resistance (ESR) capacitor across the IN pin and GND input of the regulator for improved transient performance.

Do not exceed the absolute maximum ratings.

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9 Power Supply Recommendations

The device is designed to operate from an input voltage supply range between 2 V and 5.5 V. The input voltage range provides adequate headroom for the device to have a regulated output. This input supply must be well-regulated (see 図 33 through 図 40). If the input supply is noisy, additional input capacitors with low ESR help improve the output noise performance.

10 Layout

10.1 Layout Guidelines

10.1.1 Board Layout Recommendations to Improve PSRR and Noise Performance

Place input and output capacitors as close to the device pins as possible. To improve ac performance (such as PSRR, output noise, and transient response), TI recommends that the board be designed with separate ground planes for V_{IN} and V_{OUT}, with the ground plane connected only at the GND pin of the device, as shown in 図 53. Connect the ground connection for the output capacitor directly to the GND pin of the device. High ESR capacitors can degrade PSRR performance.

10.1.2 Package Mounting

Solder pad footprint recommendations are available from the TI website at www.ti.com. The recommended land pattern for the DQN (X2SON-4) package is provided in the *メカニカル、パッケージ、および注文情報* section.

10.2 Layout Example

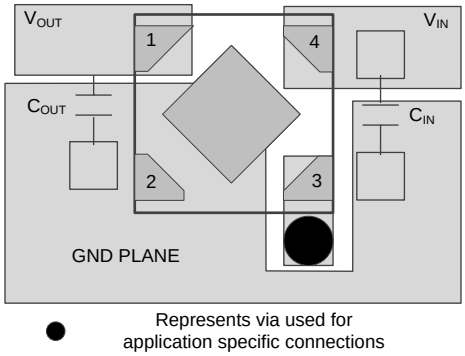

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図 53. Recommended Layout Example

10.3 Thermal Considerations

Thermal protection disables the output when the junction temperature rises to approximately 160°C, allowing the device to cool. When the junction temperature cools to approximately 140°C, the output circuitry is enables again. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the dissipation of the regulator, which protects the regulator from damage as a result of overheating.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heat sink. For reliable operation, limit junction temperature to 125°C (maximum). To estimate the margin of safety in a complete design (including heat sink), increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions.

For good reliability, thermal protection triggers at least 35°C above the maximum expected ambient condition of the particular application. This configuration produces a worst-case junction temperature of 125°C at the highest expected ambient temperature and worst-case load.

The internal protection circuitry of the LDO is designed to protect against overload conditions. This circuitry is not intended to replace proper heat sinking. Continuously running the LDO into thermal shutdown degrades device reliability.

10.4 Power Dissipation

The ability to remove heat from the die is different for each package type, presenting different considerations in the printed-circuit-board (PCB) layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air.

Performance data for JEDEC low- and high-K boards are shown in *Thermal Information*. Using heavier copper increases the effectiveness in removing heat from the device. The addition of plated through-holes to heat-dissipating layers improves heat sink effectiveness.

Power dissipation depends on input voltage and load conditions. Power dissipation (P_D) is equal to the product of the output current and the voltage drop across the output pass element, as shown in 式 2.

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \tag{2}$$

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11 デバイスおよびドキュメントのサポート

11.1 デバイス・サポート

11.1.1 開発サポート

11.1.1.1 評価モジュール

TLV742Pを使用する回路の初期性能評価に役立てるため、評価モジュール(EVM)を利用可能です。TLV70728EVM-612の設計キットおよび評価モジュールについては、*TLV70728EVM-612ユーザーズ・ガイド*を参照してください。

EVMは、テキサス・インスツルメンツのWebサイトのTLV742P製品フォルダからご請求されるか、TI eStoreから直接お求めになれます。

11.1.2 デバイスの項目表記

製品情報(1)

製品名	V_{OUT}(2)
TLV742**xx(x)*Pyyyz***	**xx(x)**は公称出力電圧です。出力電圧の分解能が100mVの場合、注文番号に2桁が使用されます。それ以外の場合は3桁が使用されます(例: 18＝1.8V、285＝2.85V)。 **P**はオプションです。Pの付いたデバイスは、アクティブ出力放電機能付きのLDOレギュレータを備えています。 **YYY**はパッケージ指定子です。 **Z**はパッケージ数量です。***R***はリール(3000ピース)、***T***はテープ(250ピース)を表します。

(1) 最新のパッケージおよび注文情報については、このドキュメントの最後にあるパッケージ・オプションの付録を参照するか、www.ti.comのデバイス製品フォルダをご覧ください。
(2) 出力電圧は、0.85Vから5Vまで、50mV刻みで利用できます。詳細と在庫については、工場にお問い合わせください。

11.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、ti.comのデバイス製品フォルダを開いてください。右上の隅にある「*通知を受け取る*」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

11.3 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™オンライン・コミュニティ ***TIのE2E（Engineer-to-Engineer）コミュニティ。***エンジニア間の共同作業を促進するために開設されたものです。e2e.ti.comでは、他のエンジニアに質問し、知識を共有し、アイディアを検討して、問題解決に役立てることができます。

設計サポート ***TIの設計サポート*** 役に立つE2Eフォーラムや、設計サポート・ツールをすばやく見つけることができます。技術サポート用の連絡先情報も参照できます。

11.4 商標

E2E is a trademark of Texas Instruments.

11.5 静電気放電に関する注意事項

すべての集積回路は、適切なESD保護方法を用いて、取扱いと保存を行うようにして下さい。

静電気放電はわずかな性能の低下から完全なデバイスの故障に至るまで、様々な損傷を与えます。高精度の集積回路は、損傷に対して敏感であり、極めてわずかなパラメータの変化により、デバイスに規定された仕様に適合しなくなる場合があります。

11.6 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV74211PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8H
TLV74211PDQNR.B	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8H
TLV74212PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8G
TLV74212PDQNR.B	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8G
TLV74215PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8F
TLV74215PDQNR.B	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8F
TLV74218PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8E
TLV74218PDQNR.B	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8E
TLV74218PDQNRG4	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8E
TLV74218PDQNRG4.B	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8E
TLV74225PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CS
TLV74225PDQNR.B	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CS
TLV74227PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8D
TLV74227PDQNR.B	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8D
TLV74228PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8C
TLV74228PDQNR.B	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8C
TLV74229PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8B
TLV74229PDQNR.B	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8B
TLV74230PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CT
TLV74230PDQNR.B	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CT
TLV74230PDQNRG4	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CT
TLV74230PDQNRG4.B	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CT
TLV74233PDQNR	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7Z
TLV74233PDQNR.B	Active	Production	X2SON (DQN) | 4	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7Z

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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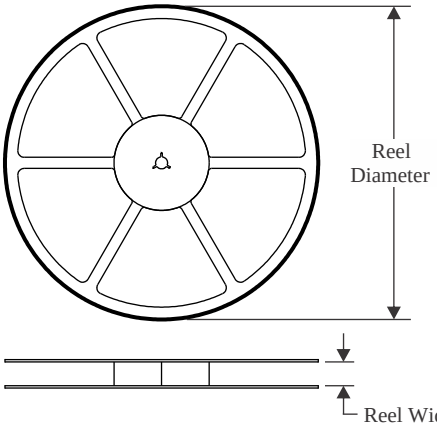
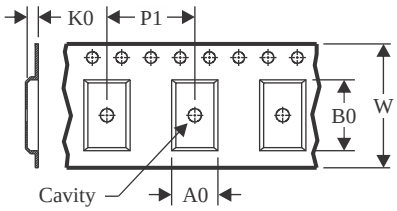
TAPE AND REEL INFORMATION

REEL DIMENSIONS

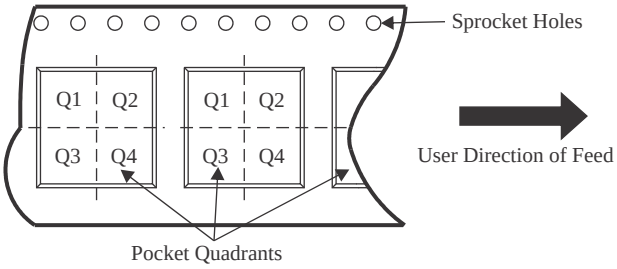


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

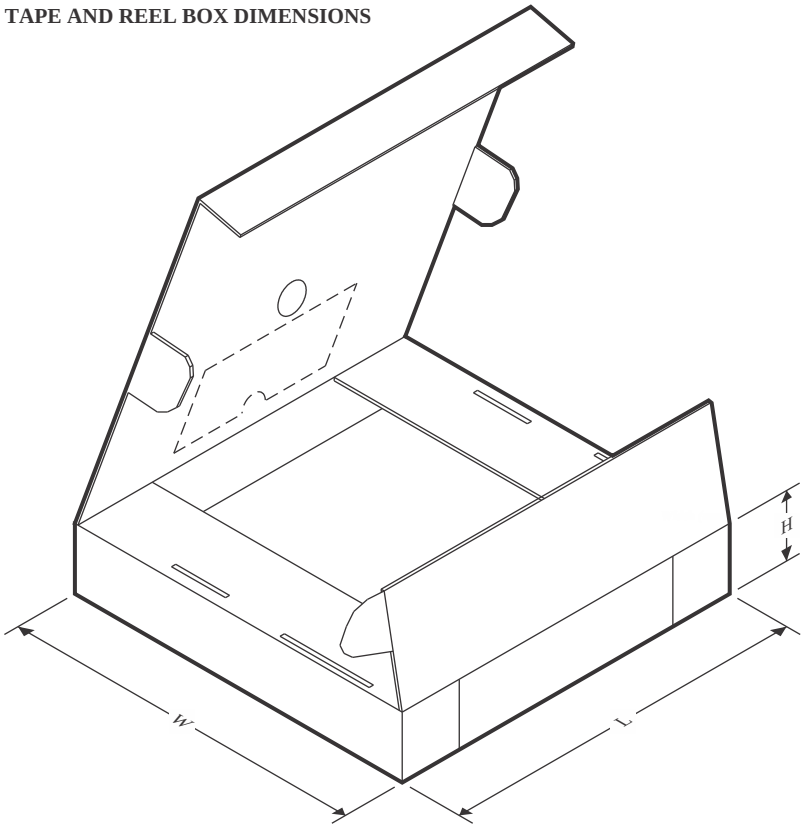
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV74211PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TLV74212PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TLV74215PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TLV74218PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TLV74218PDQNRG4	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TLV74225PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TLV74227PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TLV74228PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TLV74229PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TLV74230PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TLV74230PDQNRG4	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TLV74233PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV74211PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TLV74212PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TLV74215PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TLV74218PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TLV74218PDQNRG4	X2SON	DQN	4	3000	210.0	185.0	35.0
TLV74225PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TLV74227PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TLV74228PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TLV74229PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TLV74230PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TLV74230PDQNRG4	X2SON	DQN	4	3000	210.0	185.0	35.0
TLV74233PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0

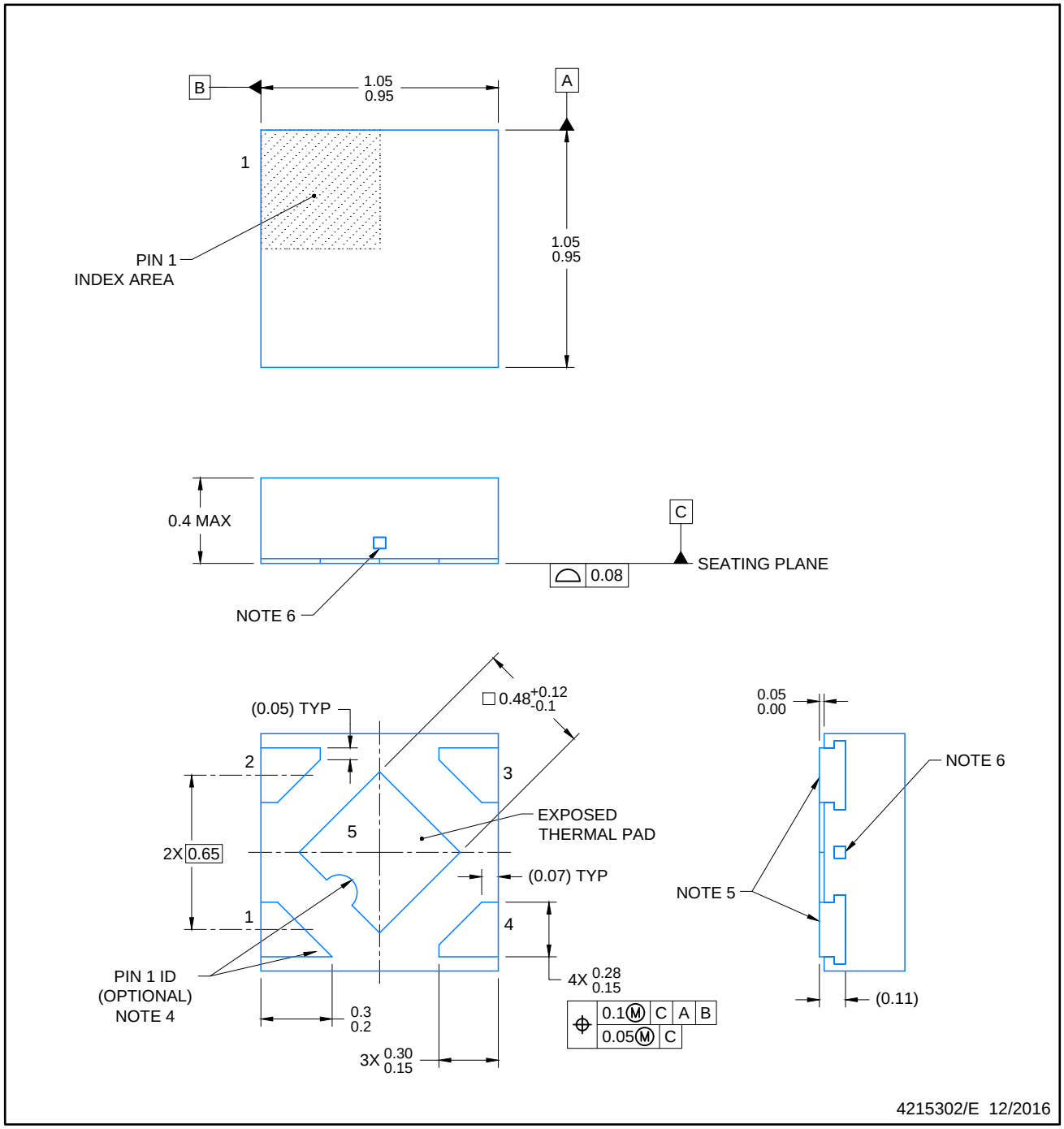
DQN 4

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

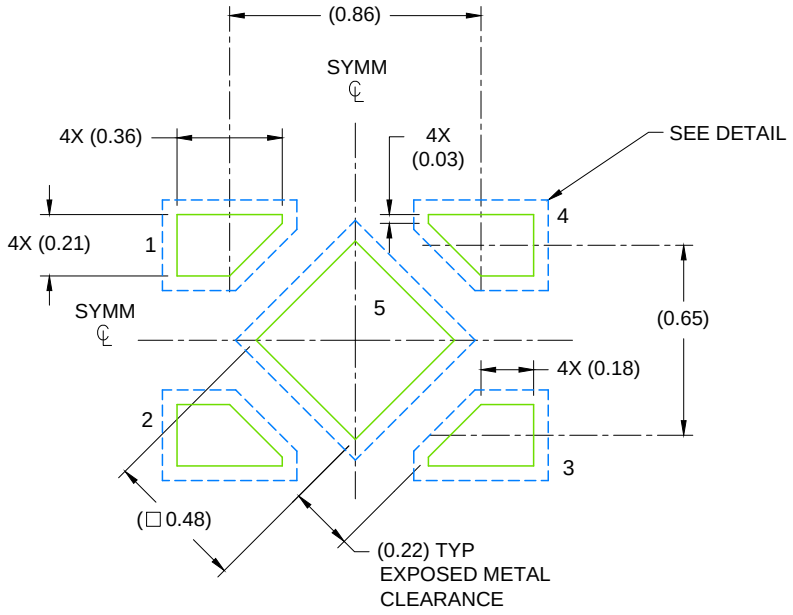
Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

TEXAS INSTRUMENTS

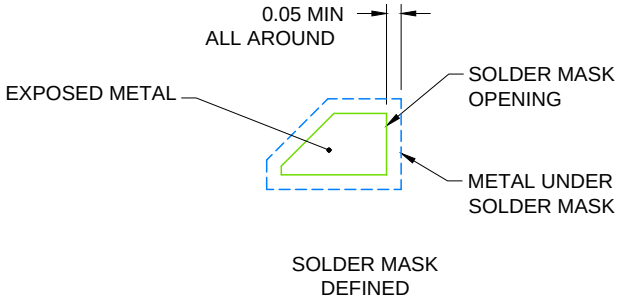


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.
4. Features may not exist. Recommend use of pin 1 marking on top of package for orientation purposes.
5. Shape of exposed side leads may differ.
6. Number and location of exposed tie bars may vary.



LAND PATTERN EXAMPLE
SCALE: 40X



SOLDER MASK DETAIL

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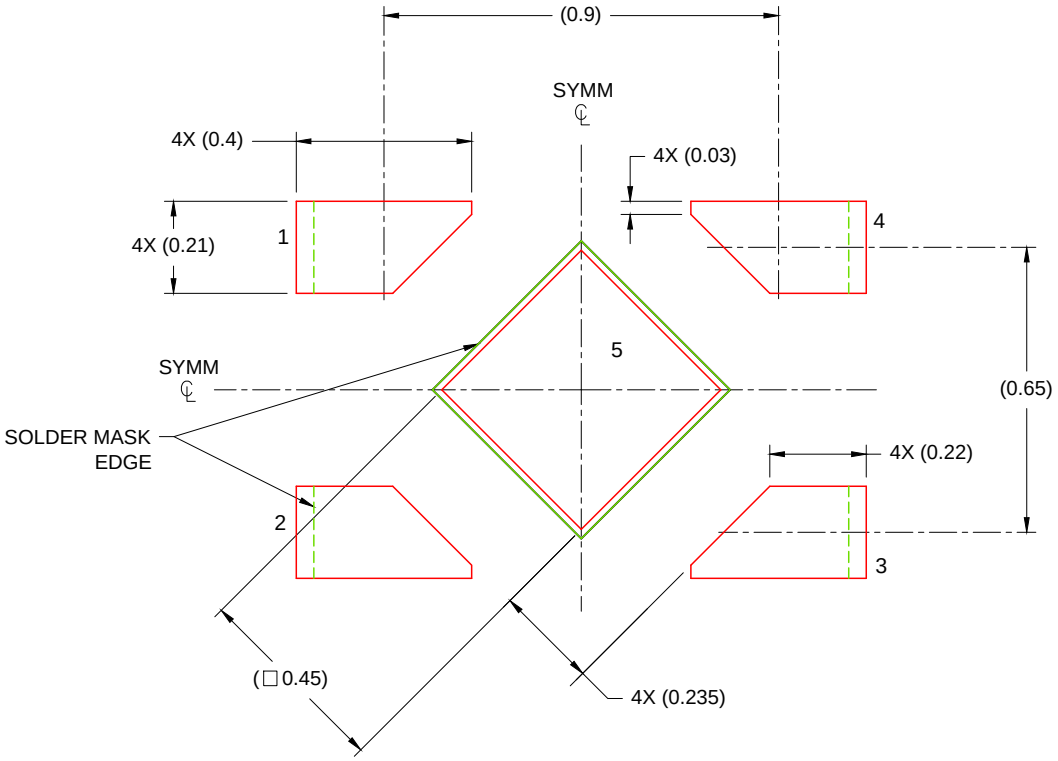
NOTES: (continued)

7. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
8. If any vias are implemented, it is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE
BASED ON 0.075 - 0.1mm THICK STENCIL

EXPOSED PAD
88% PRINTED SOLDER COVERAGE BY AREA
SCALE: 60X

4215302/E 12/2016

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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最終更新日：2025 年 10 月